

REVISIONS

LTR	DESCRIPTION	DATE (YR-MO-DA)	APPROVED

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REV STATUS OF SHEETS				REV																	
				SHEET				1	2	3	4	5	6	7	8	9	10	11	12	13	14

PMIC N/A	PREPARED BY RAJESH PITHADIA	DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		
STANDARDIZED MILITARY DRAWING THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE ANSC N/A	CHECKED BY KENNETH RICE	MICROCIRCUIT, MEMORY, DIGITAL, CMOS, ONE-TIME PROGRAMMABLE LOGIC ARRAY, MONOLITHIC SILICON		
	APPROVED BY MICHAEL FRYE			
	DRAWING APPROVAL DATE 92-11-19	SIZE A	CAGE CODE 67268	5962-91568
	REVISION LEVEL	SHEET	1	OF 21

DESC FORM 193
JUL 91

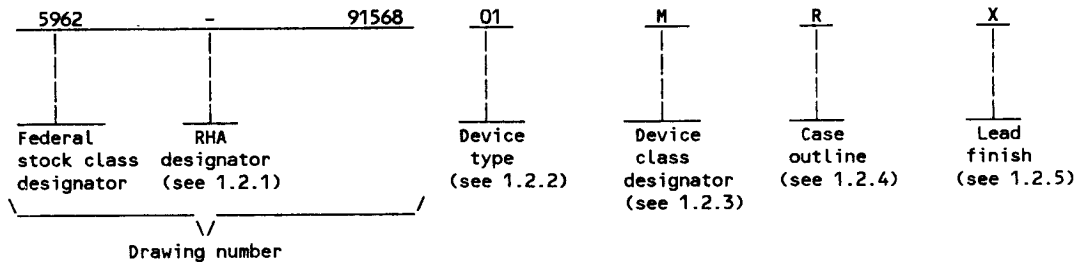
5962-E510-92

DISTRIBUTION STATEMENT A. Approved for public release; distribution is unlimited.

1. SCOPE

1.1 Scope. This drawing forms a part of a one part - one part number documentation system (see 6.6 herein). Two product assurance classes consisting of military high reliability (device classes B, Q, and M) and space application (device classes S and V) and a choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). Device class M microcircuits represent non-JAN class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices". When available, a choice of radiation hardness assurance (RHA) levels are reflected in the PIN.

1.2 PIN. The PIN shall be as shown in the following example:



1.2.1 Radiation hardness assurance (RHA) designator. Device classes M, B, and S RHA marked devices shall meet the MIL-M-38510 specified RHA levels and shall be marked with the appropriate RHA designator. Device classes Q and V RHA marked devices shall meet or exceed the electrical performance characteristics specified in table I herein after exposure to the specified irradiation levels specified in the absolute maximum ratings herein and the RHA marked device shall be marked in accordance with MIL-I-38535. A dash (-) indicates a non-RHA device.

1.2.2 Device type(s). The device type(s) shall identify the circuit function as follows:

<u>Device type</u>	<u>Generic number 1/</u>	<u>Circuit function</u>	<u>Access time</u>
01		Generic 20-pin PLD	20 ns
02		Generic 20-pin PLD	15 ns

1.2.3 Device class designator. The device class designator shall be a single letter identifying the product assurance level as follows:

<u>Device class</u>	<u>Device requirements documentation</u>
M	Vendor self-certification to the requirements for non-JAN class B microcircuits in accordance with 1.2.1 of MIL-STD-883
B or S	Certification and qualification to MIL-M-38510
Q or V	Certification and qualification to MIL-I-38535

1.2.4 Case outline(s). The case outline(s) shall be as designated in MIL-STD-1835 and as follows:

<u>Outline letter</u>	<u>Descriptive designator</u>	<u>Terminals</u>	<u>Package style</u>
R	GDIP1-T20 or CDIP2-T20	20	Dual-in-line
S	GDFP2-F20 or CDFP3-F20	20	Flat pack
X	CQCC2-N20	20	Square leadless chip carrier

1/ Generic numbers are listed on the Standardized Military Drawing Source Approval Bulletin at the end of this document and will also be listed in MIL-BUL-103.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A	5962-91568
	REVISION LEVEL	SHEET 2

1.2.5 Lead finish. The lead finish shall be as specified in MIL-M-38510 for classes M, B, and S or MIL-I-38535 for classes Q and V. Finish letter "X" shall not be marked on the microcircuit or its packaging. The "X" designation is for use in specifications when lead finishes A, B, and C are considered acceptable and interchangeable without preference.

1.3 Absolute maximum ratings. 2/ 3/

Supply voltage range to ground potential (V_{CC}) - - - - -	-0.5 V dc to +7.0 V dc
DC voltage applied to the outputs in the high Z state -	-0.5 V dc to +7.0 V dc
DC input voltage - - - - -	-3.0 V dc to +7.0 V dc
Maximum power dissipation - - - - -	1.0 W 4/
Lead temperature (soldering, 10 seconds) - - - - -	+260°C
Thermal resistance, junction-to-case (θ_{JC}) - - - - -	See MIL-STD-1835
Junction temperature (T_J) - - - - -	+175°C
Storage temperature range (T_{STG}) - - - - -	-65°C to +150°C
Temperature under bias - - - - -	-55°C to +125°C
Output current into outputs (low) - - - - -	24 mA

1.4 Recommended operating conditions.

Supply voltage range (V_{CC}) - - - - -	+4.5 V dc minimum to +5.5 V dc maximum
Ground voltage (GND) - - - - -	0.0 V dc
Input high voltage (V_{IH}) - - - - -	2.0 V dc minimum 5/
Input low voltage (V_{IL}) - - - - -	0.8 V dc maximum 5/
Case operating temperature range (T_C) - - - - -	-55°C to +125°C

1.5 Logic testing for device classes Q and V.

Fault coverage measurement of manufacturing logic tests (MIL-STD-883, test method 5012) - - - - -	6/ percent
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2. APPLICABLE DOCUMENTS

2.1 Government specifications, standards, bulletin, and handbook. Unless otherwise specified, the following specifications, standards, bulletin, and handbook of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATIONS

MILITARY

MIL-M-38510	-	Microcircuits, General Specification for.
MIL-I-38535	-	Integrated Circuits, Manufacturing, General Specification for.

STANDARDS

MILITARY

MIL-STD-480	-	Configuration Control-Engineering Changes, Deviations and Waivers.
MIL-STD-883	-	Test Methods and Procedures for Microelectronics.
MIL-STD-1835	-	Microcircuit Case Outlines.

- 2/ Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.
- 3/ All voltages referenced to V_{SS} .
- 4/ Must withstand the added P_D due to short circuit test; e.g., I_{SC} .
- 5/ These are absolute values with respect to device ground. All overshoots due to system or tester noise are included.
- 6/ Values will be added when they become available.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 3

BULLETIN

MILITARY

MIL-BUL-103 - List of Standardized Military Drawings (SMD's).

HANDBOOK

MILITARY

MIL-HDBK-780 - Standardized Military Drawings.

(Copies of the specifications, standards, bulletin, and handbook required by manufacturers in connection with specific application functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Non-Government publications. The following documents form a part of this document to the extent specified herein. Unless otherwise specified, the issues of the documents which are DoD adopted are those listed in the issue of the DODISS cited in the solicitation. Unless otherwise specified, the issues of documents not listed in the DODISS are the issues of the documents cited in the solicitation.

AMERICAN SOCIETY FOR TESTING AND MATERIALS (ASTM)

ASTM Standard F1192-88 - Standard Guide for the Measurement of Single Event Phenomena from Heavy Ion Irradiation of Semiconductor Devices.

(Applications for copies of ASTM publications should be addressed to the American Society for Testing and Materials, 1916 Race Street, Philadelphia, PA 19103).

ELECTRONICS INDUSTRIES ASSOCIATION (EIA)

JEDEC Standard No. 17 - A Standardized Test Procedure for the Characterization of Latch-up in CMOS Integrated Circuits.

(Applications for copies should be addressed to the Electronics Industries Association, 2001 Pennsylvania Street, N.W., Washington, DC 20006.)

(Non-Government standards and other publications are normally available from the organizations that prepare or distribute the documents. These documents also may be available in or through libraries or other informational services.)

2.3 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements for device class M shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein. The individual item requirements for device classes B and S shall be in accordance with MIL-M-38510 and as specified herein. This is a fully characterized military detail specification and is suitable for qualification of devices classes B and S to the requirements of MIL-M-38510. The individual item requirements for device classes Q and V shall be in accordance with MIL-I-38535, the device manufacturer's Quality Management (QM) Plan, and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 for device classes M, B, and S and MIL-I-38535 for device classes Q and V and herein.

3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.4 herein.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.

3.2.3 Truth table. The truth table shall be as specified on figure 2.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 4

DESC FORM 193A
JUL 91

3.2.3.1 Unprogrammed devices. The truth table for unprogrammed devices for contracts involving no altered item drawing shall be as specified on figure 2. When required in screening (see 4.2 herein), or qualification conformance inspection groups A, B, C, or D (see 4.3 herein), the devices shall be programmed by the manufacturer prior to test in a checkerboard or similar pattern (a minimum of 50 percent of the total number of gates programmed).

3.2.3.2 Programmed devices. The truth table for programmed devices shall be as specified by an attached altered item drawing.

3.3 Electrical performance characteristics and postirradiation parameter limits. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full case operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table IIA. The electrical tests for each subgroup are defined in table I.

3.5 Verification of programmability. When specified, devices shall be verified as programmed (see 4.5 herein) to the specified pattern. As a minimum, verification shall consist of performing a functional test (subgroup 7) to verify that all bits are in the proper state. Any bit that does not verify to be in the proper state shall constitute a device failure, and shall be removed from the lot.

3.6 Processing options. Since the device is capable of being programmed by either the manufacturer or the user to result in a wide variety of configurations; two processing options are provided for selection in the contract.

3.6.1 Unprogrammed device delivered to the user. All testing shall be verified through group A testing as defined in 3.2.3.1 and table IIA. It is recommended that users perform subgroups 7 and 9 after programming to verify the specific program configuration.

3.6.2 Manufacturer-programmed device delivered to the user. All testing requirements and quality assurance provisions herein, including the requirements of the altered item drawing, shall be satisfied by the manufacturer prior to delivery.

3.7 Marking. The part shall be marked with the PIN listed in 1.2 herein. Marking for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein). In addition, the manufacturer's PIN may also be marked as listed in MIL-BUL-103. Marking for device classes B and S shall be in accordance with MIL-M-38510. Marking for device classes Q and V shall be in accordance with MIL-I-38535.

3.7.1 Certification/compliance mark. The compliance mark for device class M shall be a "C" as required in MIL-STD-883 (see 3.1 herein). The certification mark for device classes B and S shall be a "J" or "JAN" as required in MIL-M-38510. The certification mark for device classes Q and V shall be a "QML" as required in MIL-I-38535.

3.8 Certificate of compliance. For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-BUL-103 (see 6.7.3 herein). For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.7.2 herein). The certificate of compliance submitted to DESC-EC prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device class M the requirements of MIL-STD-883 (see 3.1 herein), or for device classes Q and V, the requirements of MIL-I-38535 and the requirements herein.

3.9 Certificate of conformance. A certificate of conformance as required for device class M in MIL-STD-883 (see 3.1 herein) or device classes B and S in MIL-M-38510 or for device classes Q and V in MIL-I-38535 shall be provided with each lot of microcircuits delivered to this drawing.

3.10 Notification of change for device class M. For device class M, notification to DESC-EC of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change as defined in MIL-STD-480.

3.11 Verification and review for device class M. For device class M, DESC, DESC's agent and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

3.12 Microcircuit group assignment for device classes M, B, and S. Device classes M, B, and S devices covered by this drawing shall be in microcircuit group number 42 (see MIL-M-38510, appendix E).

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 5

DESC FORM 193A
JUL 91

TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	
Output high voltage	V _{OH}	V _{CC} = 4.5 V, I _{OH} = -2.0 mA, V _{IN} = V _{IH} and V _{IL}	1, 2, 3	ALL	2.4		V
Output low voltage	V _{OL}	V _{CC} = 4.5 V, I _{OL} = 12 mA, V _{IN} = V _{IH} and V _{IL}	1, 2, 3	ALL		0.5	V
Input high voltage <u>1/</u>	V _{IH}		1, 2, 3	ALL	2.0		V
Input low voltage <u>1/</u>	V _{IL}		1, 2, 3	ALL		0.8	V
Input leakage current	I _{IX}	V _{CC} = 5.5 V, V _{IN} = 5.5 V to GND	1, 2, 3	ALL	-10	10	μA
Output leakage current	I _{OZ}	V _{CC} = 5.5 V, V _{OUT} = 5.5 V to GND	1, 2, 3	ALL	-40	40	μA
Output short circuit current <u>2/ 3/</u>	I _{SC}	V _{CC} = 5.5 V, V _{OUT} = 0.5 V	1, 2, 3	ALL	-30	-90	mA
Power supply current	I _{CC}	V _{CC} = 5.5 V, I _{OUT} = 0 mA, V _{IN} = GND	1, 2, 3	ALL		110	mA
Input capacitance <u>3/</u>	C _{IN}	V _{CC} = 5.0 V, T _A = +25°C, f = 1 MHz, (See 4.4.1f)	4	ALL		10	pF
Output capacitance <u>3/</u>	C _{OUT}		4	ALL		10	pF
Functional tests		See 4.4.1c	7,8	ALL			
Input or feedback to nonregistered output	t _{PD}	See figures 3 (circuit A) and 4. <u>4/</u>	9, 10, 11	01		20	ns
				02		15	
Clock to output	t _{CO}		9, 10, 11	01		15	ns
				02		12	
Input to output enable <u>3/</u>	t _{EA}		9, 10, 11	01		20	ns
				02		15	

See footnotes at end of table.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 6

DESC FORM 193A
JUL 91

TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	
Input to output disable <u>3/</u> <u>5/</u>	t _{ER}	See figures 3 (circuit B) and 4. <u>4/</u>	9, 10, 11	01		20	ns
				02		15	
Input or feedback setup time	t _S	See figures 3 (circuit A) and 4. <u>4/</u>	9, 10, 11	01	15		ns
				02	12		
Hold time	t _H		9, 10, 11	ALL	0		ns
Clock period (t _S + t _{CO})	t _P		9, 10, 11	01	35		ns
				02	27		
Clock width high	t _{WH}		9, 10, 11	01	10		ns
				02	9		
Clock width low <u>3/</u>	t _{WL}		9, 10, 11	01	11		ns
				02	10		
Maximum frequency 1/(t _{CO} + t _{WL}) <u>6/</u>	f _{MAX}		9, 10, 11	01	33.3		MHz
				02	41.6		
Pin 11 to output enable	t _{PZX}	See figures 3 (circuit B) and 4. <u>4/</u>	9, 10, 11	01		15	ns
				02		12	
Pin 11 to output disable <u>5/</u>	t _{PXZ}		9, 10, 11	01		15	ns
				02		10	

- 1/ These are absolute values with respect to device ground and all overshoots and undershoots due to system or tester noise are included.
- 2/ For test purposes, not more than one output at a time should be shorted. Short circuit test duration should not exceed 1 second. V_{OUT} = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.
- 3/ Tested initially and after any design or process changes that affect that parameter, and therefore shall be guaranteed to the limits specified in table I.
- 4/ AC tests are performed with input rise and fall times of 5 ns or less, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0 V, and the output loads on figure 3.
- 5/ This delay is measured to the point at which a previous high level has fallen to 0.5 volt below V_{OH} minimum or a previous low level has risen to 0.5 volt above V_{OH} maximum.
- 6/ f_{MAX}, minimum guaranteed operating frequency, is that guaranteed for state machine operation and is calculated from f_{MAX} = 1/(t_S + t_{CO}). The minimum guaranteed f_{MAX} for registered data path operation (no feedback) can be calculated as the lower of 1/(t_{WH} + t_{WL}) or 1/(t_S + t_H).

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 7

DESC FORM 193A
JUL 91

3.13 Serialization for device class S and V. All device class S devices shall be serialized in accordance with MIL-M-38510. Class V shall be serialized in accordance with MIL-I-38535.

4. QUALITY ASSURANCE PROVISIONS

4.1 Sampling and inspection. For device class M, sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein). For device classes B and S, sampling and inspection procedures shall be in accordance with MIL-M-38510 and method 5005 of MIL-STD-883, except as modified herein. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-I-38535.

4.2 Screening. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. For device classes B and S, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to qualification and quality conformance inspection. For device classes Q and V, screening shall be in accordance with MIL-I-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection.

4.2.1 Additional criteria for device classes M, B, and S.

- a. Delete the sequence specified as initial (pre-burn-in) electrical parameters through interim (post-burn-in) electrical parameters of method 5004 and substitute lines 1 through 6 of table IIA herein.
- b. For device class M, the burn-in test circuit shall be submitted to DESC-EC for review with the certificate of compliance. For device classes B and S, the burn-in test circuit shall be submitted to the qualifying activity.

(1) Static burn-in for device class S (method 1015 of MIL-STD-883, test condition A).

- a. All inputs shall be connected to GND. Outputs may be open or connected to 4.5 V minimum. Resistors R1 are optional on both inputs and outputs, and required on outputs connected to $V_{CC} \pm 0.5$ V. $R1 = 220$ ohms to 47 kohms. For static II burn-in, reverse all input connections (i.e., V_{SS} to V_{CC}).
- b. $V_{CC} = 4.5$ V minimum.
- c. Ambient temperature (T_A) shall be +125°C minimum.
- d. Test duration for the static test shall be 48 hours minimum. The 48-hour burn-in shall be broken into two sequences of 24 hours each (static I and static II) followed by interim electrical measurements.

(2) Dynamic burn-in for device classes M, B, and S (method 1015 of MIL-STD-883, test condition D) using the circuit submitted.

- c. Interim and final electrical parameters shall be as specified in table IIA herein.
- d. For class S and B devices, post dynamic burn-in electrical parameter measurements may, at the manufacturer's option, be performed separately or included in the final electrical parameter requirements.
- e. A data retention stress test shall be included as part of the screening procedure and shall consist of the following steps: (Steps 1 through 4 are performed at the wafer level.)

- (1) Program 100 percent of the total number of cells, excluding the security bit.
- (2) Bake, unbiased, for 72 hours at +140°C or for 48 hours at +150°C or for 8 hours at +200°C, or 2 hours at +300°C for unassembled devices only.
- (3) Perform margin test using $V_m = +5.7$ V at +25°C using loose timing (i.e., $t_{ACC} = 1 \mu s$).
- (4) Erase.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 8

DESC FORM 193A
JUL 91

4.2.2 Additional criteria for device classes Q and V.

- a. The burn-in test duration, test condition and test temperature or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The burn-in test circuit shall be submitted to DESC-EC with the certificate of compliance and shall be under the control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-I-38535.
- b. Interim and final electrical test parameters shall be as specified in table IIA herein.
- c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in appendix B of MIL-I-38535 and as detailed in table IIB herein.
- d. Additional requirements beyond MIL-I-38535 for classes Q and V are specified in table IIA herein.

4.2.3 Percent Defective Allowable (PDA).

- a. The PDA for class S devices shall be 5 percent for static burn-in and 5 percent for dynamic burn-in, based on the exact number of devices submitted to each separate burn-in.
- b. The PDA for class B devices shall be in accordance with MIL-M-38510 for dynamic burn-in.
- c. Static burn-in I and II failures shall be cumulative for determining PDA.
- d. Those devices whose measured characteristics, after burn-in, exceed the specified delta limits or electrical parameter limits specified in table I, subgroup 1, are defective and shall be removed from the lot. The verified failures divided by the total number of devices in the lot initially submitted to burn-in shall be used to determine the percent defective for the lot and the lot shall be accepted or rejected based on the specified PDA.
- e. The PDA for device classes Q and V shall be in accordance with MIL-I-38535 for dynamic burn-in.

4.3 Qualification inspection.

4.3.1 Qualification inspection for device classes B and S. Qualification inspection for device classes B and S shall be in accordance with MIL-M-38510. Inspections to be performed shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5). Qualification data for subgroups 7, 8A, and 8B shall be attributes only.

4.3.1.1 Qualification extension for device class B and S. When authorized by the qualifying activity, if a manufacturer qualifies one device type which is identical (i.e., same die), to other device types on this drawing, the slower device types may be part I qualified, upon the request of the manufacturer, without any further testing. The faster device types may be part I qualified by performing only group A qualification testing.

4.3.2 Qualification inspection for device classes Q and V. Qualification inspection for device classes Q and V shall be in accordance with MIL-I-38535. Inspections to be performed shall be those specified in MIL-I-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5).

4.4 Conformance inspection. Quality conformance inspection for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein) and as specified herein. Quality conformance inspection for device classes B and S shall be in accordance with MIL-M-38510 and as specified herein. Inspections to be performed for device classes M, B, and S shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5). Technology conformance inspection for classes Q and V shall be in accordance with MIL-I-38535 including groups A, B, C, D, and E inspections and as specified herein.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 9

Device types	All
Case outlines	All
Terminal number	Terminal symbol
1	CP/I
2	I
3	I
4	I
5	I
6	I
7	I
8	I
9	I
10	GND
11	OE/I
12	I/O
13	I/O
14	I/O
15	I/O
16	I/O
17	I/O
18	I/O
19	I/O
20	V _{CC}

FIGURE 1. Terminal connections.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 10

DESC FORM 193A
JUL 91

Input pins										Output pins							
CP	$\overline{\text{OE}}$	I	I	I	I	I	I	I	I	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O
X	X	X	X	X	X	X	X	X	X	Z	Z	Z	Z	Z	Z	Z	Z

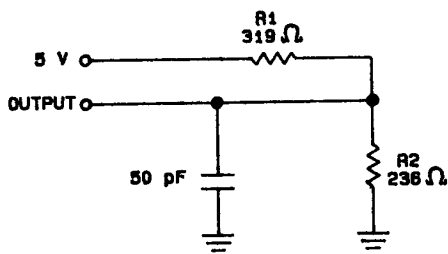
NOTES:

1. Z = three-state.
2. X = don't care.

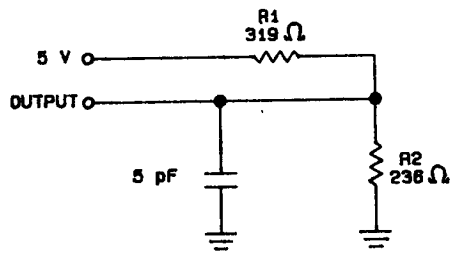
FIGURE 2. Truth table.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 11

DESC FORM 193A
JUL 91



CIRCUIT A
OUTPUT LOAD



CIRCUIT B
OUTPUT LOAD

*Including scope and jig (minimum value).

AC test conditions

Input pulse levels	GND to 3.0 V
Input rise and fall times	≤ 5 ns
Input timing reference levels	1.5 V
Output reference levels	1.5 V

FIGURE 3. Output load circuits and test conditions.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 12

DESC FORM 193A
JUL 91

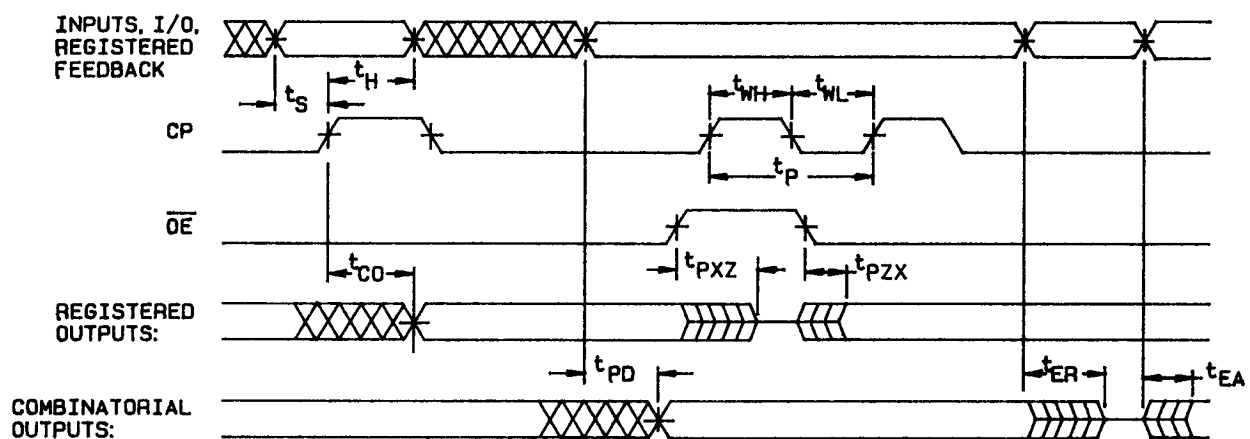


FIGURE 4. Timing waveform.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 13

DESC FORM 193A
JUL 91

4.4.1 Group A inspection.

- a. Tests shall be as specified in table IIA herein.
- b. Subgroups 5 and 6 of table I of method 5005 of MIL-STD-883 shall be omitted.
- c. For device class M, subgroups 7 and 8 tests shall be sufficient to verify the truth table. For device classes B and S, subgroups 7 and 8 tests shall be sufficient to verify the truth table as approved by the qualifying activity. For device classes Q and V, subgroups 7 and 8 shall include verifying the functionality of the device. These tests shall have been fault graded in accordance with MIL-STD-883, test method 5012 (see 1.5 herein).
- d. Devices shall be tested for programmability and ac performance compliance to the requirements of group A, subgroups 9, 10, and 11.
 - (1) A sample shall be selected to satisfy programmability requirements prior to performing subgroups 9, 10, and 11. Twelve devices shall be submitted to programming (see 3.2.3.1). If more than two devices fail to program, the lot shall be rejected. At the manufacturer's option, the sample may be increased to 24 total devices with no more than 4 total device failures allowable.
 - (2) Ten devices from the programmability sample shall be submitted to the requirements of group A, subgroups 9, 10, and 11. If more than two devices fail, the lot shall be rejected. At the manufacturer's option, the sample may be increased to 20 total devices with no more than 4 total device failures allowable.
- e. O/V (latch-up) tests shall be measured only for initial qualification and after any design or process changes which may affect the performance of the device. For device class M, procedures and circuits shall be maintained under document revision level control by the manufacturer and shall be made available to the preparing activity or acquiring activity upon request. For device classes B and S, the procedures and circuits shall be maintained under document revision control by the manufacturer and shall be made available to the qualifying activity upon request. For device classes Q and V, procedures and circuits shall be under the control of the device manufacturer's technical review board (TRB) in accordance with MIL-I-38535 and shall be made available to the preparing activity or acquiring activity upon request. Testing shall be on all pins, on five devices with zero failures. Latch-up test shall be considered destructive. Information contained in JEDEC standard number 17 may be used for reference.
- f. Subgroup 4 (C_{IN} and C_{OUT} measurements) shall be measured only for initial qualification and after any process or design changes which may affect input or output capacitance. Capacitance shall be measured between the designated terminal and GND at a frequency of 1 MHz. Sample size is 15 devices with no failures, and all input and output terminals tested.

4.4.2 Group B inspection. The group B inspection end-point electrical parameters shall be as specified in table IIA herein.

- a. For device class S, steady-state life test shall be conducted using test condition D and the circuit described in 4.2.1b herein, or equivalent as approved by the qualifying activity.
- b. For device class S only, end-point electrical parameters shall be as specified in table IIA herein. Delta limits shall apply only to subgroup 5 of group B inspections and shall consist of tests specified in table IIC herein.
- c. All devices selected for class S electrical testing shall be programmed with a checkerboard pattern or equivalent.

4.4.3 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table IIA herein. Delta limits shall apply only to subgroup 1 of group C inspections and shall consist of tests specified in table IIC herein.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 14

DESC FORM 193A
JUL 91

4.4.3.1 Additional criteria for device classes M and B.

a. Steady-state life test conditions, method 1005 of MIL-STD-883:

- (1) The devices selected for testing shall be programmed with a checkerboard pattern.
- (2) Test condition D. For device class M, the test circuit shall be submitted to DESC-EC for review with the certificate of compliance. For device classes B and S, the test circuit shall be submitted to the qualifying activity.
- (3) $T_A = +125^\circ\text{C}$, minimum.
- (4) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

4.4.3.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The steady-state life test circuit shall be submitted to DESC-EC with the certificate of compliance and shall be under the control of the device manufacturer's TRB in accordance with MIL-I-38535.

4.4.4 Group D inspection. For group D inspection, end-point electrical parameters shall be as specified in table IIA herein. The devices selected for testing shall be programmed with a checkerboard pattern.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 15

DESC FORM 193A
 JUL 91

TABLE IIA. Electrical test requirements. 1/ 2/ 3/ 4/ 5/ 6/

Line no.	Test requirements	Subgroups (per method 5005 table I)			Subgroups (per MIL-I-38535, table III)	
		Device class M	Device class B	Device class S	Device class Q	Device class V
1	Interim electrical parameters (see 4.2)		1,7,9 or 2,8A,10	1,7,9 or 2,8A,10		1,7,9 or 2,8A,10
2	Static burn-in method 1015	Not required	Not required	Required	Not required	Required
3	Same as line 1			1*,7* Δ		1*,7* Δ
4	Dynamic burn-in (method 1015)	Required	Required	Required	Required	Required
5	Same as line 1			1*,7* Δ		1*,7* Δ
6	Final electrical parameters (unprogrammed devices)	1*,2,3,7*,8A,8B	1*,2,3,7*,8A,8B	1*,2,3,7*,8A,8B	1*,2,3,7*,8A,8B	1*,2,3,7*,8A,8B
6A	Final electrical parameters (programmed devices)	1*,2,3,7*,8A,8B,9,10,11	1*,2,3,7*,8A,8B,9,10,11	1*,2,3,7*,8A,8B,9,10,11	1*,2,3,7*,8A,8B,9,10,11	1*,2,3,7*,8A,8B,9,10,11
7	Group A test requirements	1,2,3,4**,7,8A,8B,9,10,11	1,2,3,4**,7,8A,8B,9,10,11	1,2,3,4**,7,8A,8B,9,10,11	1,2,3,4**,7,8A,8B,9,10,11	1,2,3,4**,7,8A,8B,9,10,11
8	Group B end-point electrical parameters			1,2,3,7,8A,8B,9,10,11 Δ		
9	Group C end-point electrical parameters	2,3,7,8A,8B	1,2,3,7,8A,8B,9,10,11 Δ		1,2,3,7,8A,8B,9,10,11 Δ	1,2,3,7,8A,8B,9,10,11 Δ
10	Group D end-point electrical parameters	2,3,7,8A,8B	2,3,7,8A,8B	2,3,7,8A,8B	2,3,7,8A,8B	2,3,7,8A,8B
11	Group E end-point electrical parameters	1,7,9	1,7,9	1,7,9	1,7,9	1,7,9

- 1/ Blank spaces indicate tests are not applicable.
- 2/ Any or all subgroups may be combined when using high-speed testers.
- 3/ Subgroups 7 and 8 functional tests shall also verify that no cells are programmed for unprogrammed devices or that the altered item drawing pattern exists for programmed devices (see table IIA).
- 4/ * indicates PDA applies to subgroups 1 and 7.
- 5/ ** see 4.4.1f.
- 6/ Δ indicates delta limit (see table IIC) shall be required where specified, and the delta values shall be computed with reference to the previous interim electrical parameters (line 1).

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 16

DESC FORM 193A
JUL 91

TABLE IIB. Additional screening for device class V.

Test	MIL-STD-883, test method	Lot requirement
Particle impact noise detection	2020	100 percent
Internal visual	2010, condition A or approved alternate	100 percent
Nondestructive bond pull	2023 or approved alternate	100 percent
Reverse bias burn-in	1015	100 percent
Burn-in parameters	1015, total of 240 hours at +125° C	100 percent
Radiographic	2012	100 percent

TABLE IIC. Delta limits at +25°C.

Parameter ^{1/}	Device types
	All
I_{IX}	±1.0 μ A of specified value in table I
I_{OZ}	±4.0 μ A of specified value in table I

^{1/} The above parameter shall be recorded before and after the required burn-in and life tests to determine the delta.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 17

DESC FORM 193A
JUL 91

4.4.5 Group E inspection. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.7 herein). RHA levels for device classes B, S, Q, and V shall be M, D, R, and H and for device class M shall be M and D. RHA quality conformance inspection sample tests shall be performed at the RHA level specified in the acquisition document or to a higher qualified level. RHA tests for device classes Q and V shall be performed in accordance with MIL-I-38535 and 1.2.1 herein.

- a. RHA tests for device classes B, S, Q and V for levels M, D, R, and H or for device class M for levels M and D shall be performed through each level to determine at what levels the devices meet the RHA requirements. These RHA tests shall be performed for initial qualification and after design or process changes which may affect the RHA performance of the device.
- b. End-point electrical parameters shall be as specified in table IIA herein. RHA samples need not be tested at -55°C or +125°C prior to total dose irradiation.
- c. Prior to total dose irradiation, each selected sample shall be assembled in its qualified package. The samples shall pass the specified group A electrical parameters in table IA for subgroups specified in table IIA herein. Additionally classes Q and V, for quality conformance inspection may be at wafer level.
- d. The devices shall be subjected to radiation hardness assured tests as specified in MIL-M-38510 (device classes M, B, and S) and MIL-I-38535 (device classes Q and V) for the RHA level being tested, and meet the postirradiation end-point electrical parameter limits as defined in table I at $T_A = +25^\circ\text{C} \pm 5^\circ\text{C}$, after exposure.
- e. Prior to and during total dose irradiation testing, the devices shall be biased to the worst case conditions established during characterization.
- f. Single Event Phenomena (SEP) testing, shall be performed on all class S and V devices. SEP testing shall be performed at initial qualification and after any design or process changes which may affect the upset or latch-up characteristics of the device. Test four devices with zero failures. ASTM standard F1192-88 may be used as a guideline when performing SEP testing. For device class V, the device parameters that influence single event upset immunity shall be monitored at the wafer level as part of a TRB approved wafer level hardness plan. The test conditions for SEP are as follows:
 - (1) The ion beam angle of incidence shall be between normal to the die surface and 60° to the normal, inclusive (i.e., $0^\circ \leq \text{angle} \leq 60^\circ$). No shadowing of the ion beam due to fixturing or package related effects is allowed.
 - (2) The fluence shall be $\geq 10^7$ ions/cm².
 - (3) The flux shall be between 10^2 and 10^5 ion/cm²/s. The cross section shall be verified to be flux independent by measuring the cross section at two flux rates which differ by at least an order of magnitude.
 - (4) The particle range shall be ≥ 20 microns in silicon.
 - (5) The test temperature shall be +25°C and the maximum rated operating temperature $\pm 10^\circ\text{C}$.
 - (6) Bias conditions shall be $V_{CC} = 4.5$ V dc for the upset measurements and $V_{CC} = 5.5$ V dc for the latch-up measurements.
- g. For device classes M, B, and S, subgroups 1 and 2 of table V method 5005 of MIL-STD-883 shall be tested as appropriate for device construction.
- h. Transient dose rate upset testing for class Q and V devices shall be performed as specified by TRB approved radiation hardness assurance plan and MIL-I-38535. Device parametric parameters that influence upset immunity shall be monitored at the wafer level in accordance with the wafer level hardness assurance plan and MIL-I-38535.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 18

DESC FORM 193A
JUL 91

- i. Transient dose rate survivability testing for class Q and V devices shall be performed as specified by a TRB approved radiation hardness assurance plan and MIL-I-38535. Device parametric parameters that influence latch-up and device burn-out shall be monitored at the wafer level in accordance with the wafer level hardness assurance plan and MIL-I-38535.
- j. When specified in the acquisition document or contract, a copy of the following additional data shall be supplied.
 - (1) RHA delta limits.
 - (2) RHA upset levels.
 - (3) Test conditions (SEP).
 - (4) Number of upsets (SEP).
 - (5) Number of transients.
 - (6) Occurrence of latch-up.

4.5 Programming procedure. The programming procedures shall be as specified by the device manufacturer and shall be made available upon request.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510 for device classes M, B, and S and MIL-I-38535 for device classes Q and V.

6. NOTES

(This section contains information of a general or explanatory nature that may be helpful, but is not mandatory.)

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.1.2 Substitutability. Device classes B and Q devices will replace device class M devices.

6.2 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-481 using DD Form 1693, Engineering Change Proposal (Short Form).

6.3 Record of users. Military and industrial users shall inform Defense Electronics Supply Center when a system application requires configuration control and which SMD's are applicable to that system. DESC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DESC-EC, telephone (513) 296-6047.

6.4 Comments. Comments on this drawing should be directed to DESC-EC, Dayton, Ohio 45444, or telephone (513) 296-5377.

6.5 Symbols, definitions, and functional descriptions.

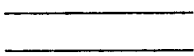

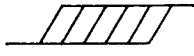
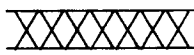
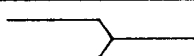
C _{IN} - - - - -	Input terminal capacitance.
C _{OUT} - - - - -	Output terminal capacitance.
GND - - - - -	Ground zero voltage potential.
I _{CC} - - - - -	Supply current.
I _{IX} - - - - -	Input current.
I _{OZ} - - - - -	Output current.
T _C - - - - -	Case temperature.
V _{CC} - - - - -	Positive supply voltage.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 19

DESC FORM 193A
JUL 91

6.5.1 Timing limits. The table of timing values shows either a minimum or a maximum limit for each parameter. Input requirements are specified from the external system point of view. Thus, address setup time is shown as a minimum since the system must supply at least that much time (even though most devices do not require it). On the other hand, responses from the memory are specified from the device point of view. Thus, the access time is shown as a maximum since the device never provides data later than that time.

6.5.2 Waveforms.

WAVEFORM SYMBOL	INPUT	OUTPUT
	MUST BE VALID	WILL BE VALID
	CHANGE FROM H TO L	WILL CHANGE FROM H TO L
	CHANGE FROM L TO H	WILL CHANGE FROM L TO H
	DON'T CARE ANY CHANGE PERMITTED	CHANGING STATE UNKNOWN
		HIGH IMPEDANCE

6.6 One part - one part number system. The one part - one part number system described below has been developed to allow for transitions between identical generic devices covered by the four major microcircuit requirements documents (MIL-M-38510, MIL-H-38534, MIL-I-38535, and 1.2.1 of MIL-STD-883) without the necessity for the generation of unique PIN's. The four military requirements documents represent different class, and previously when a device manufacturer upgraded military product from one class level to another, the benefits of the upgraded product were unavailable to the Original Equipment Manufacturer (OEM), who was contractually locked into the original unique PIN. By establishing a one part number system covering all four documents, the OEM can procure to the highest class level available for a given generic device to meet system needs without modifying the original contract parts selection criteria.

<u>Military documentation format</u>	<u>Example PIN under new system</u>	<u>Manufacturing source listing</u>	<u>Document Listing</u>
New MIL-M-38510 Military Detail Specifications (in the SMD format)	5962-XXXXZZ(B or S)YY	QPL-38510 (Part 1 or 2)	MIL-BUL-103
New MIL-H-38534 Standardized Military Drawings	5962-XXXXZZ(H or K)YY	QML-38534	MIL-BUL-103
New MIL-I-38535 Standardized Military Drawings	5962-XXXXZZ(Q or V)YY	QML-38535	MIL-BUL-103
New 1.2.1 of MIL-STD-883 Standardized Military Drawings	5962-XXXXZZ(M)YY	MIL-BUL-103	MIL-BUL-103

6.7 Sources of supply.

6.7.1 Sources of supply for device classes B and S. Sources of supply for device classes B and S are listed in QPL-38510.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 20

DESC FORM 193A
JUL 91

6.7.2 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.8 herein) to DESC-EC and have agreed to this drawing.

6.7.3 Approved sources of supply for device class M. Approved sources of supply for class M are listed in MIL-BUL-103. The vendors listed in MIL-BUL-103 have agreed to this drawing and a certificate of compliance (see 3.8 herein) has been submitted to and accepted by DESC-EC.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-91568
		REVISION LEVEL	SHEET 21

DESC FORM 193A
JUL 91